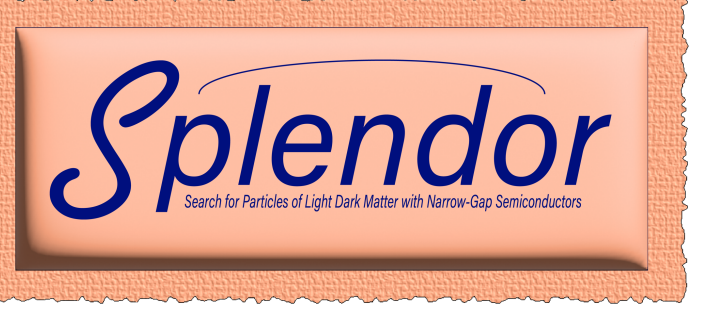


Searching for Light Dark Matter with Narrow-gap Semiconductors: The SPLENDOR Experiment



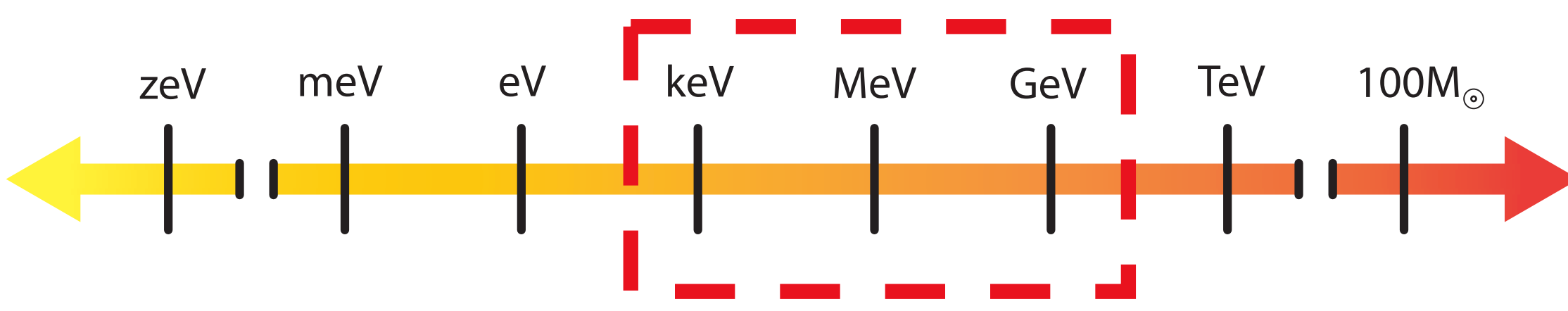
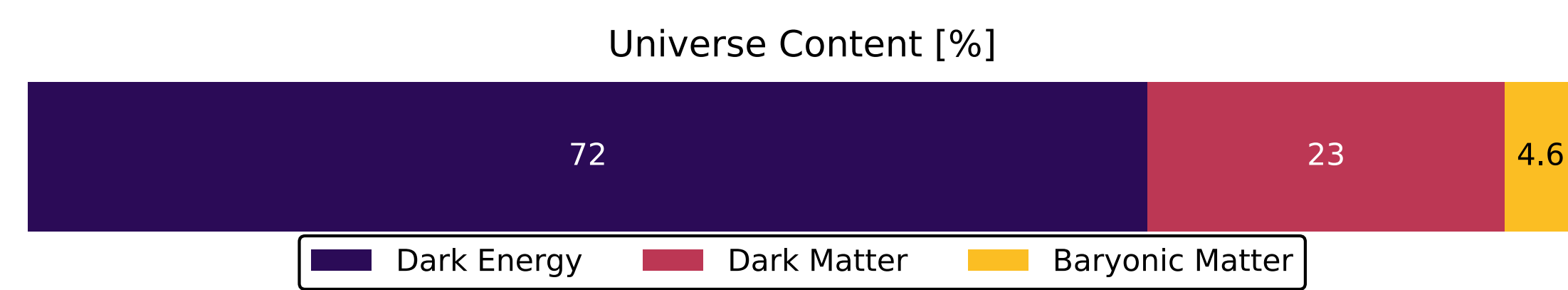
Samuel L. Watkins, for the SPLENDOR Collaboration | Los Alamos National Laboratory, Los Alamos, NM 87545, USA



SPLENDOR

The SPLENDOR (Search for Particles of Light Dark Matter with Narrow-gap Semiconductors) experiment is a search for light dark matter via the electron-recoil interaction channel, taking advantage of novel single-crystal narrow-bandgap (order 10-100 meV) semiconductors. Synthesized within the collaboration, the properties of these designer materials imply low dark counts when operated as ionization detectors at cryogenic temperatures. Using a readout scheme based on low-noise cryogenic high electron mobility transistors (HEMTs), the experiment is on track to achieve $O(1)$ electron-hole pair resolution. This provides an excellent opportunity to probe new light dark matter parameter space: down to sub-MeV masses for fermionic dark matter and sub-eV masses for bosonic dark matter. This poster reviews the multidisciplinary R&D behind SPLENDOR, discusses the current status of the experiment, and presents projected sensitivities for a planned dark matter search.

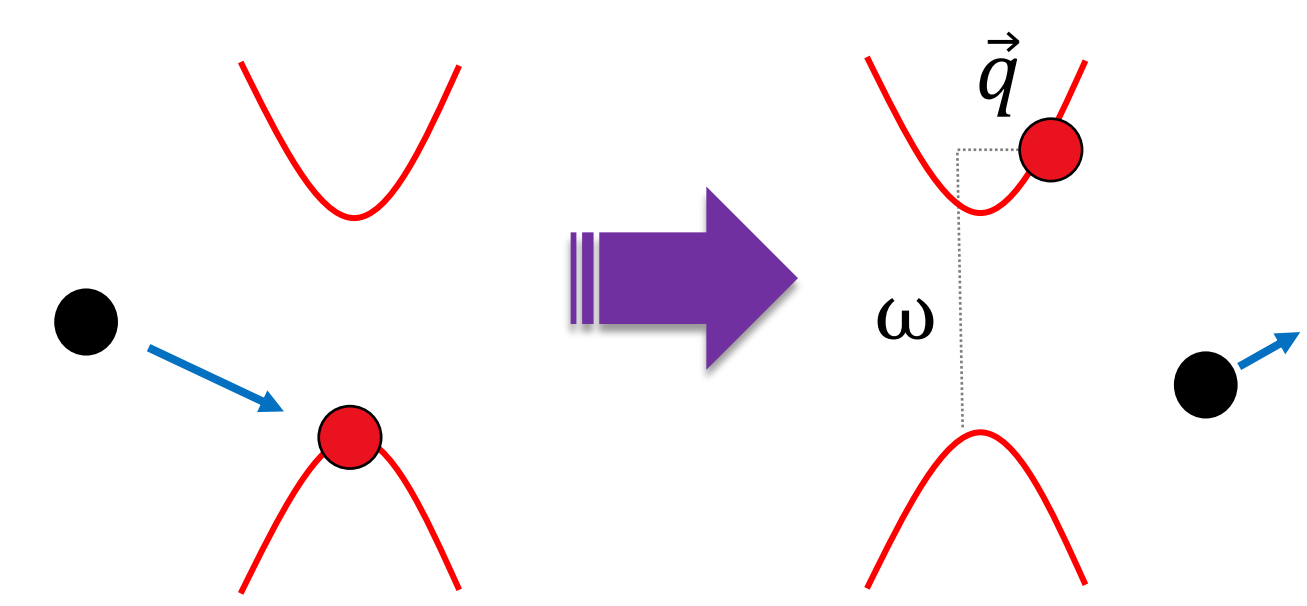
Light Dark Matter



THE DARK SECTOR

- Kinematically-mixed dark photon
- Bosonic dark matter
- Asymmetric dark matter
- Freeze-in dark matter
- *Insert your favorite candidate here*

DM-ELECTRON SCATTERING



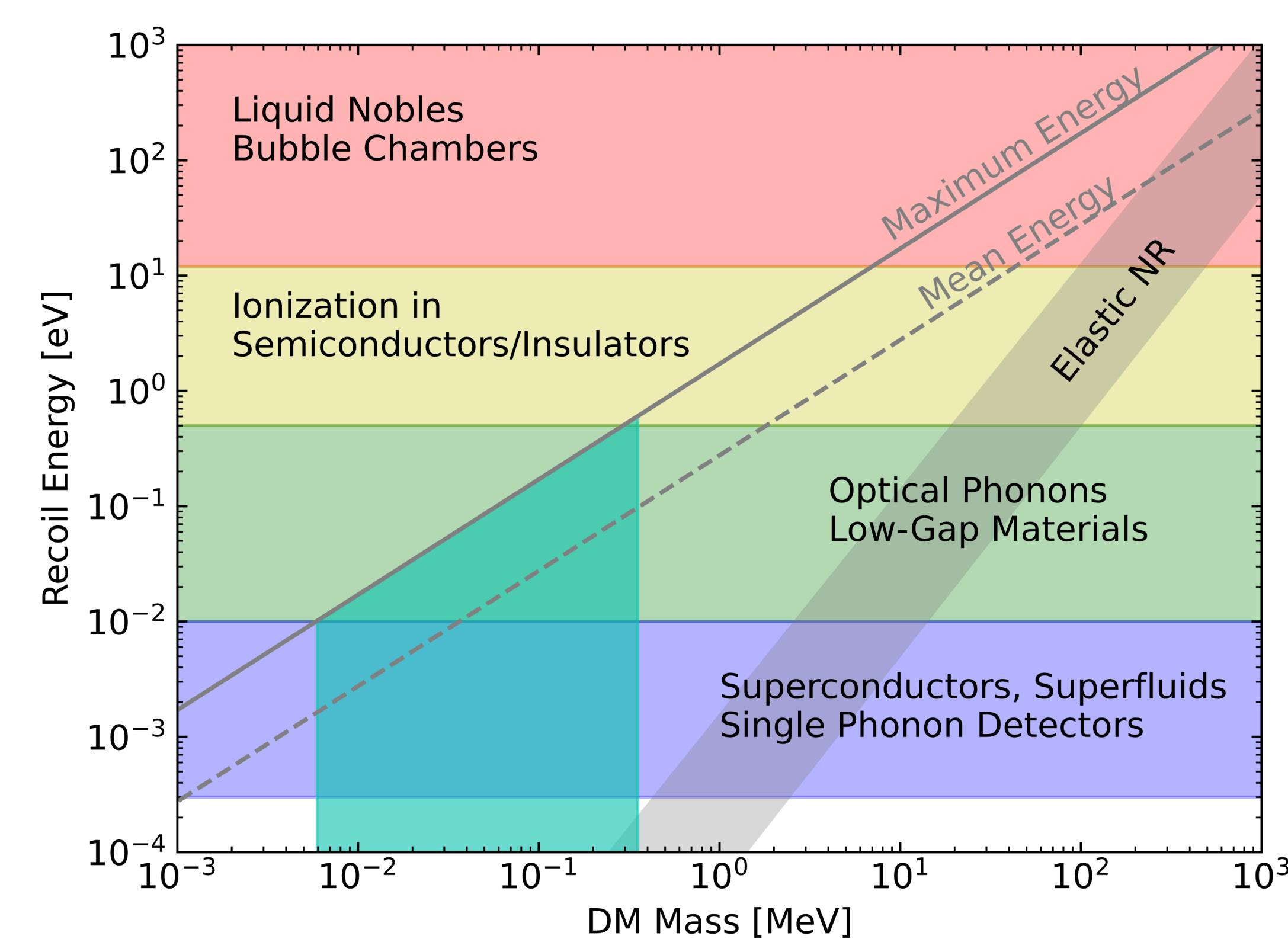
- Inelastic scattering process
- Can be formulated in terms of the experimentally measurable and theoretically calculable **Loss Function**

$$\Gamma(\mathbf{v}_\chi) = \int \frac{d^3\mathbf{q}}{(2\pi)^3} |V(\mathbf{q})|^2 \left[2 \frac{q^2}{e^2} \text{Im} \left(-\frac{1}{\epsilon(\mathbf{q}, \omega_{\mathbf{q}})} \right) \right]$$

$$\mathcal{W}(\mathbf{q}, \omega) \equiv \text{Im} \left(-\frac{1}{\epsilon(\mathbf{q}, \omega)} \right)$$

Y Hochberg *et al*, *Phys. Rev. Lett.* **127**, 151802 (2021).

WHY NARROW BANDGAPS?



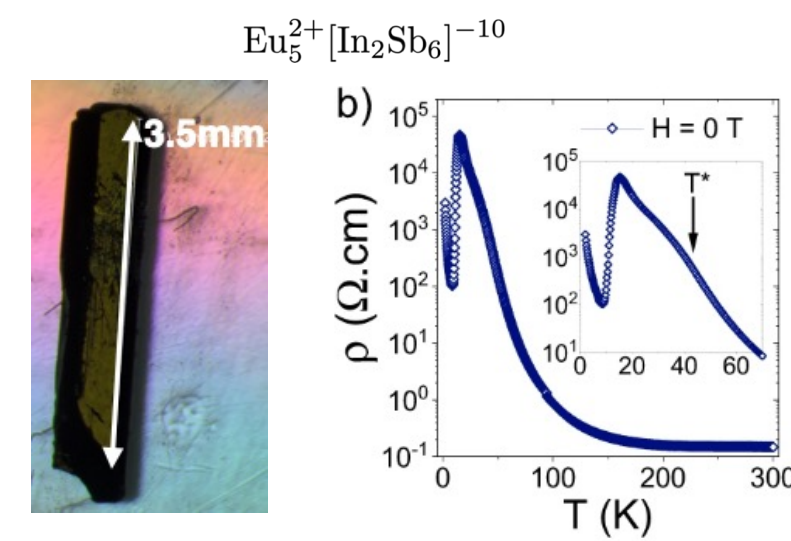
Recoil energy scales and detection technology. Adapted from arXiv:2203.08297

- Light dark matter searches via DM-electron scattering are fundamentally limited by bandgap
- With novel materials with small (order 10-100 meV) bandgaps, we can search for sub-MeV fermionic dark matter and sub-eV bosonic dark matter

Materials Approach

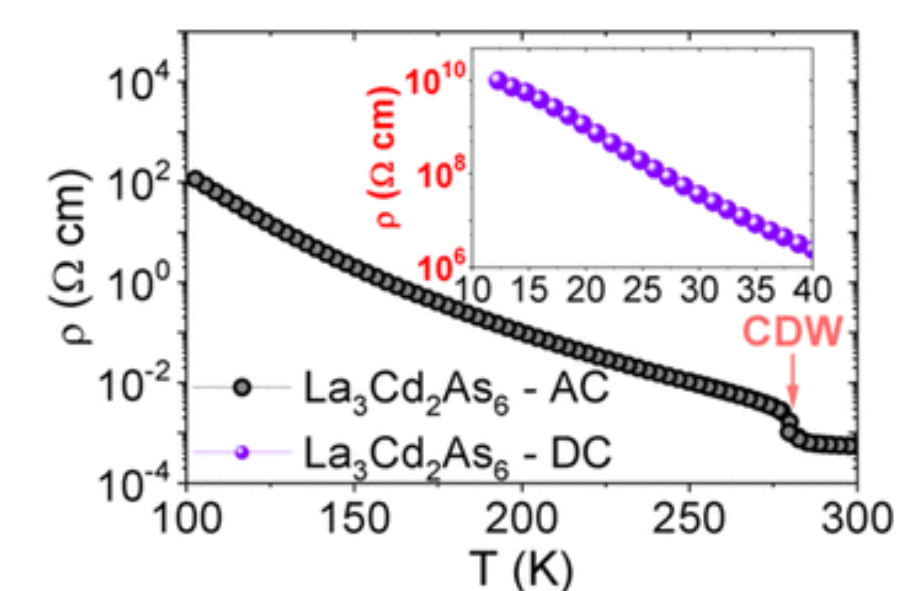
IN-HOUSE MATERIALS DISCOVERY

Electron count/Zintl phases



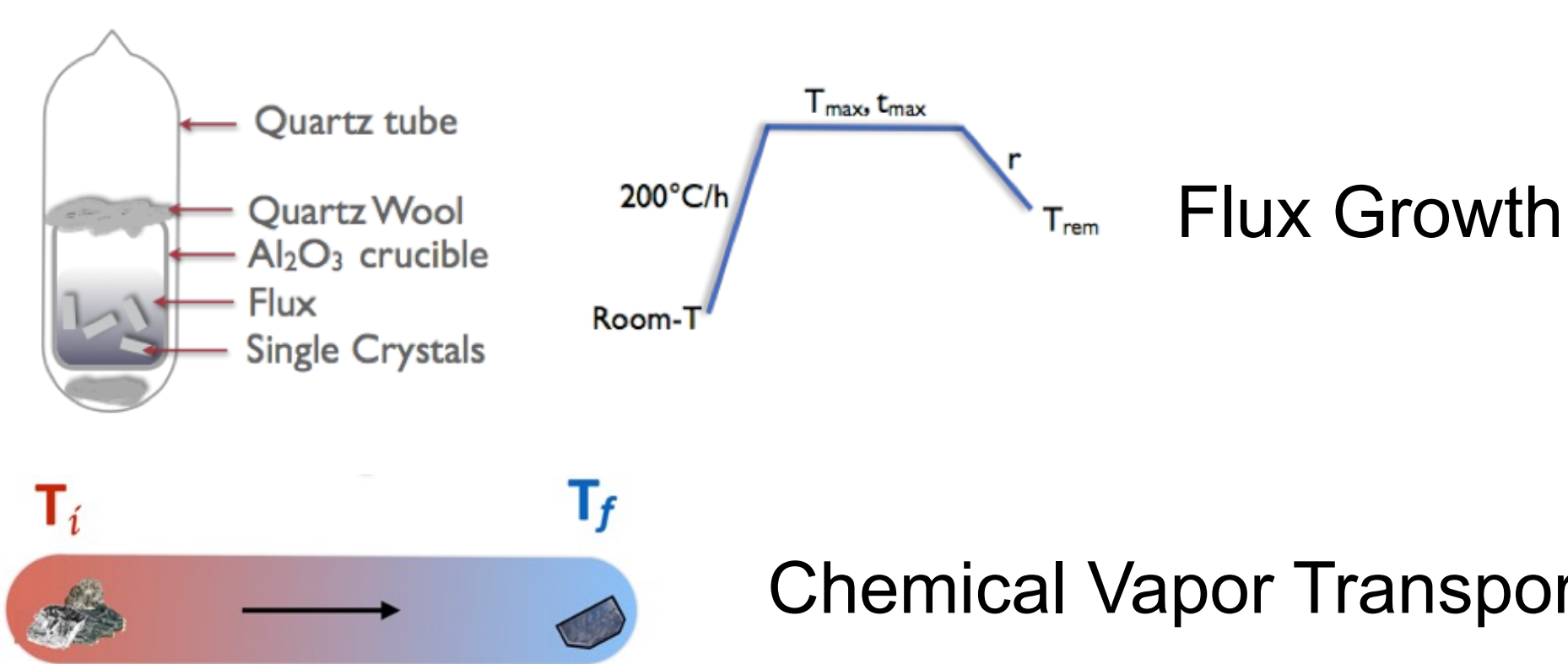
PFS Rosa *et al*, *npj Quantum Materials* **5**, 52 (2020).

Charge density wave

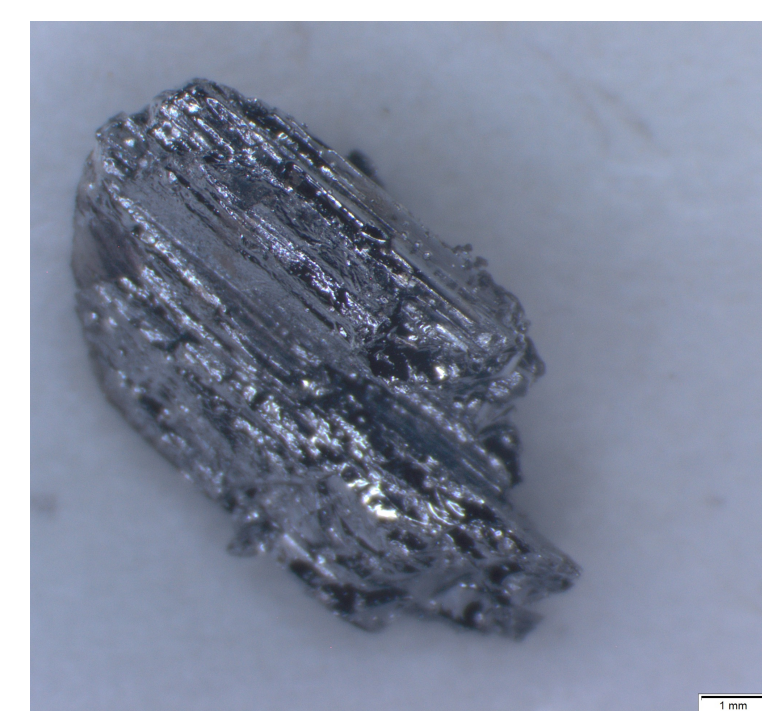


MM Piva *et al*, *Chem. Mater.* **33**, 11, 4122 (2021).

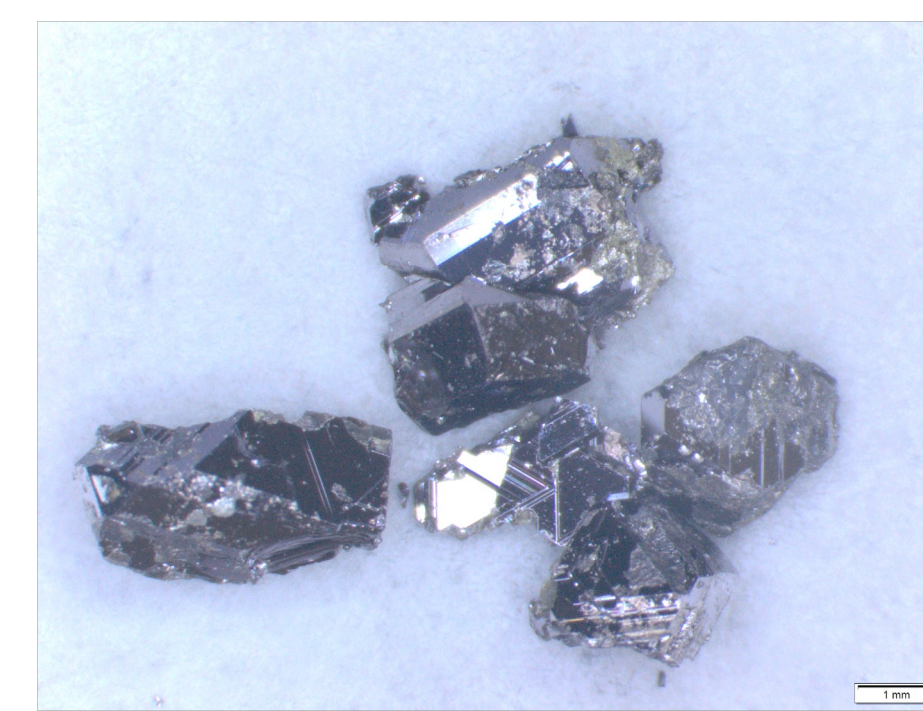
IN-HOUSE MATERIALS GROWTH



SOME CANDIDATE MATERIALS

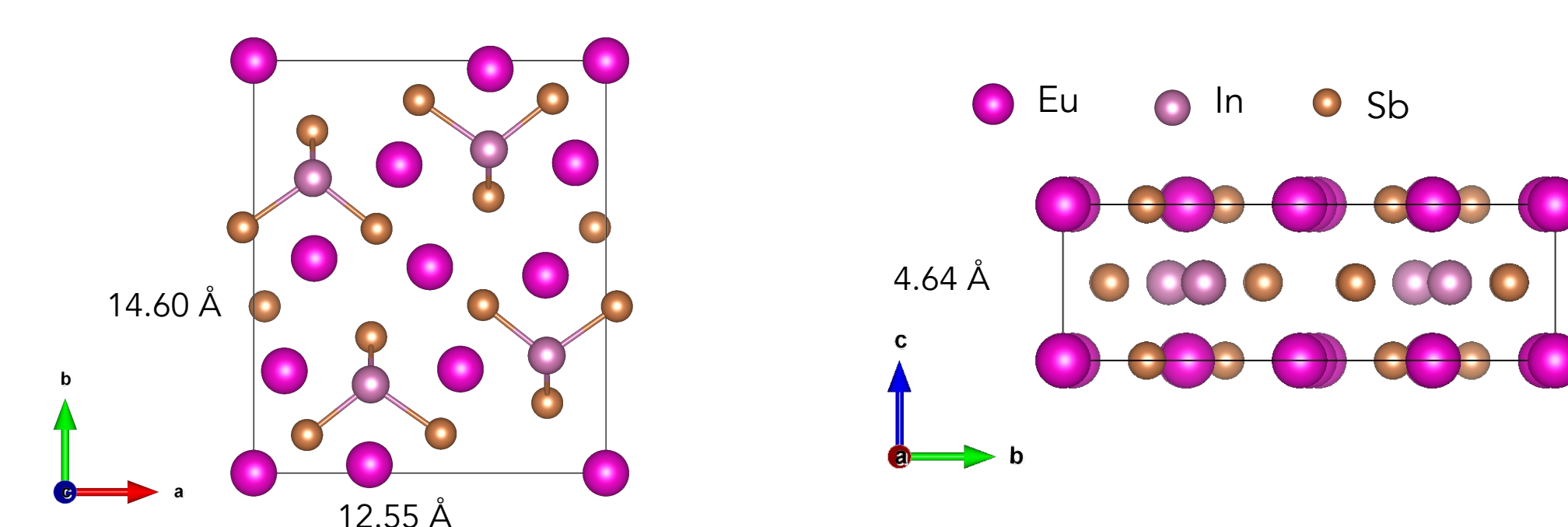


Eu₅In₂Sb₆



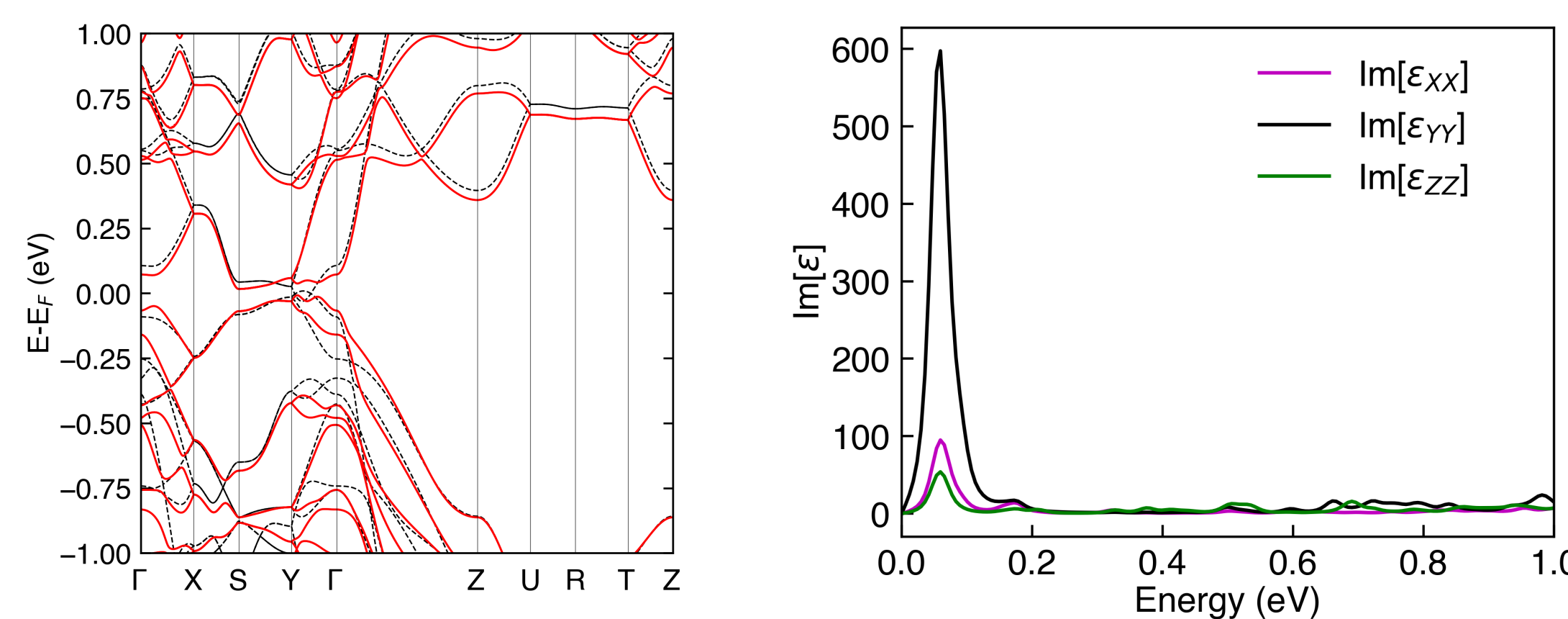
EuZn₂P₂

Eu₅In₂Sb₆: A Case Study

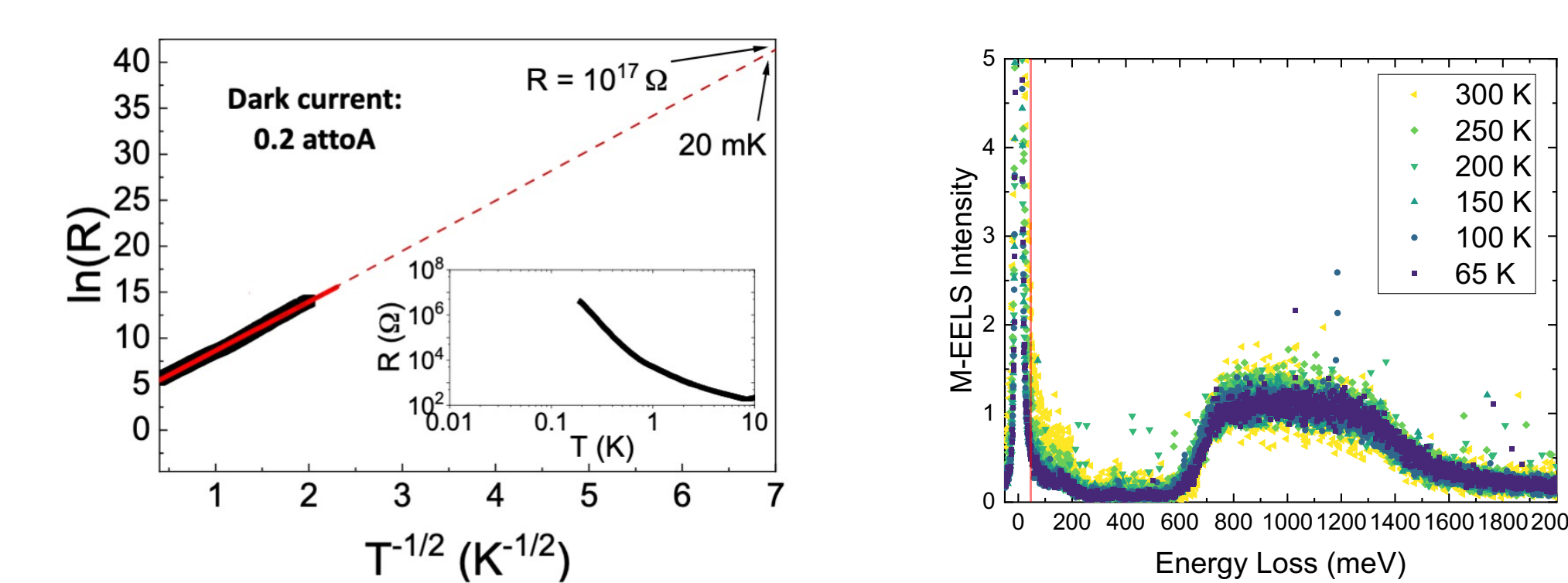


MATERIALS THEORY

- Use many-body perturbation theory to calculate loss function from **first principles**



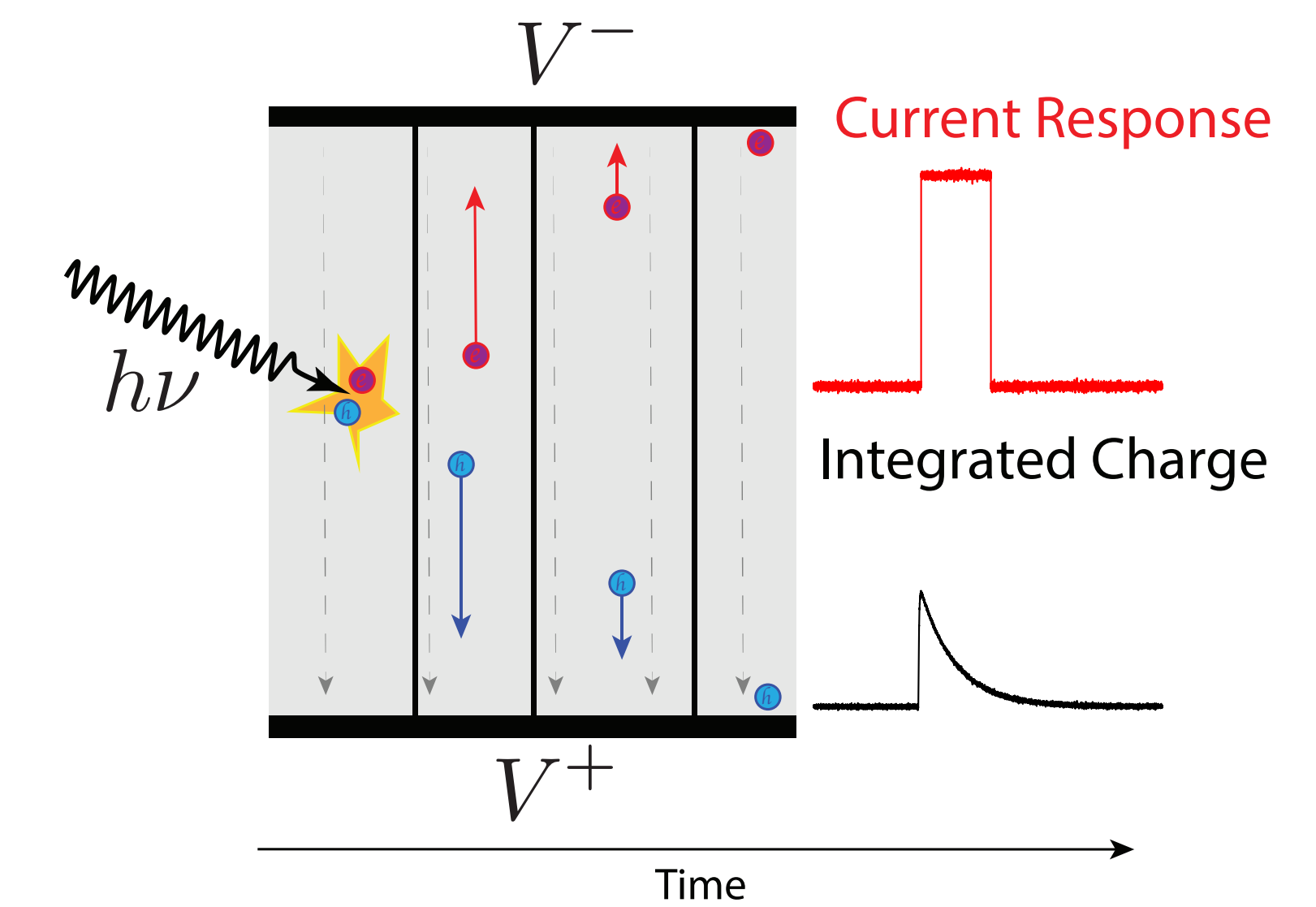
MATERIALS EXPERIMENT



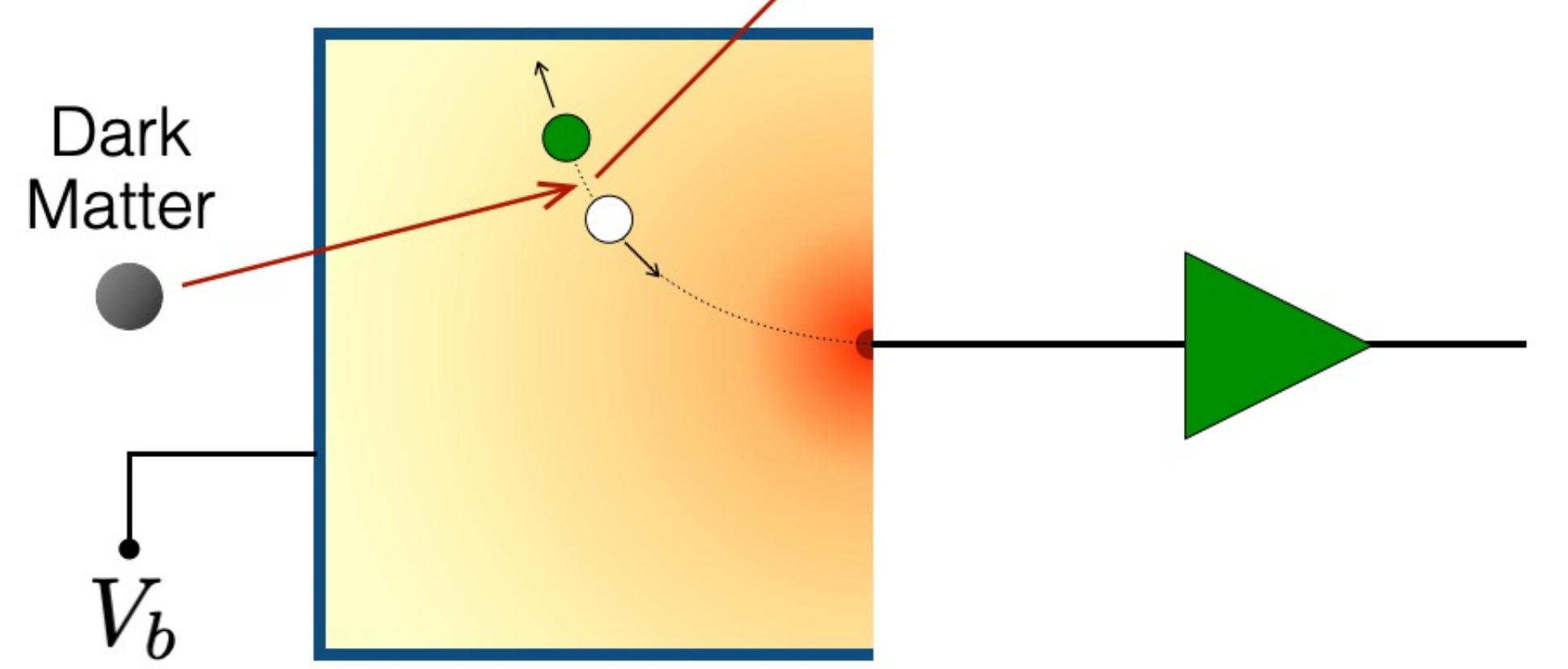
- Resistivity measurements indicate gaps of order 100 meV and very low dark counts
- EELS measurements allow direct measurement of loss function via experiment, and for direct comparison to theory

Detection Scheme

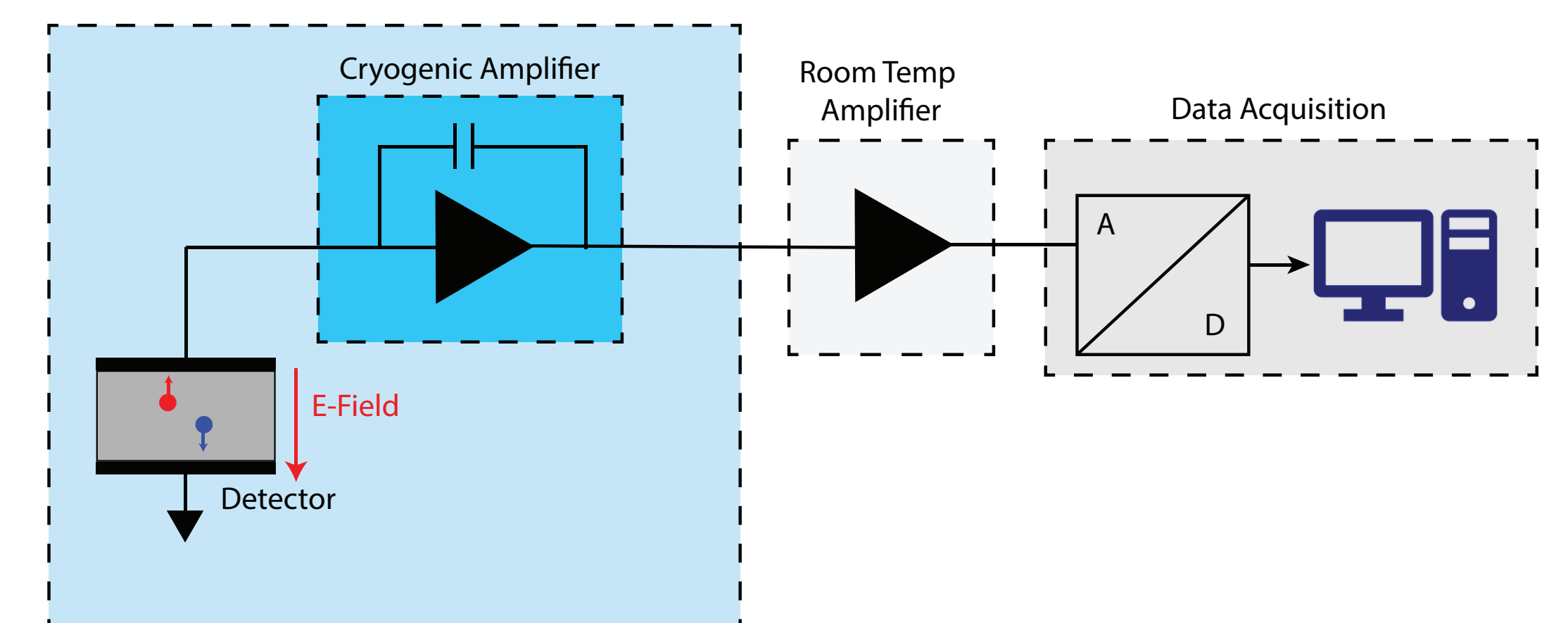
CHARGE AMPLIFICATION PRINCIPLES



- Use well-known point-contact style detector design

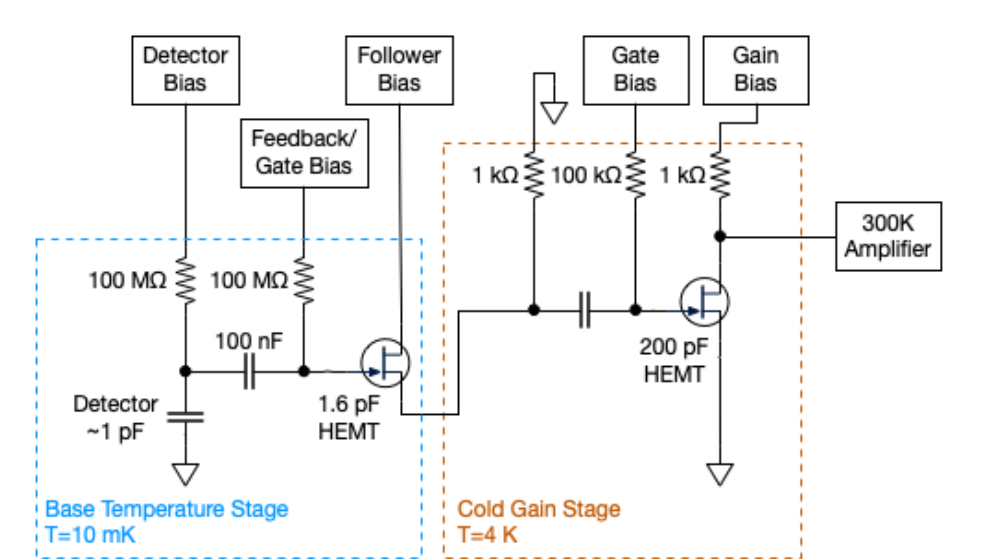


READOUT CHAIN



$$\sigma_E \sim E_{gap} \times \underbrace{\sigma_V \times (C_{detector} + C_{input} + C_{parasitic})}_{\text{charge resolution (goal: } \sigma_{e^-} \sim O(1) e^-)}$$

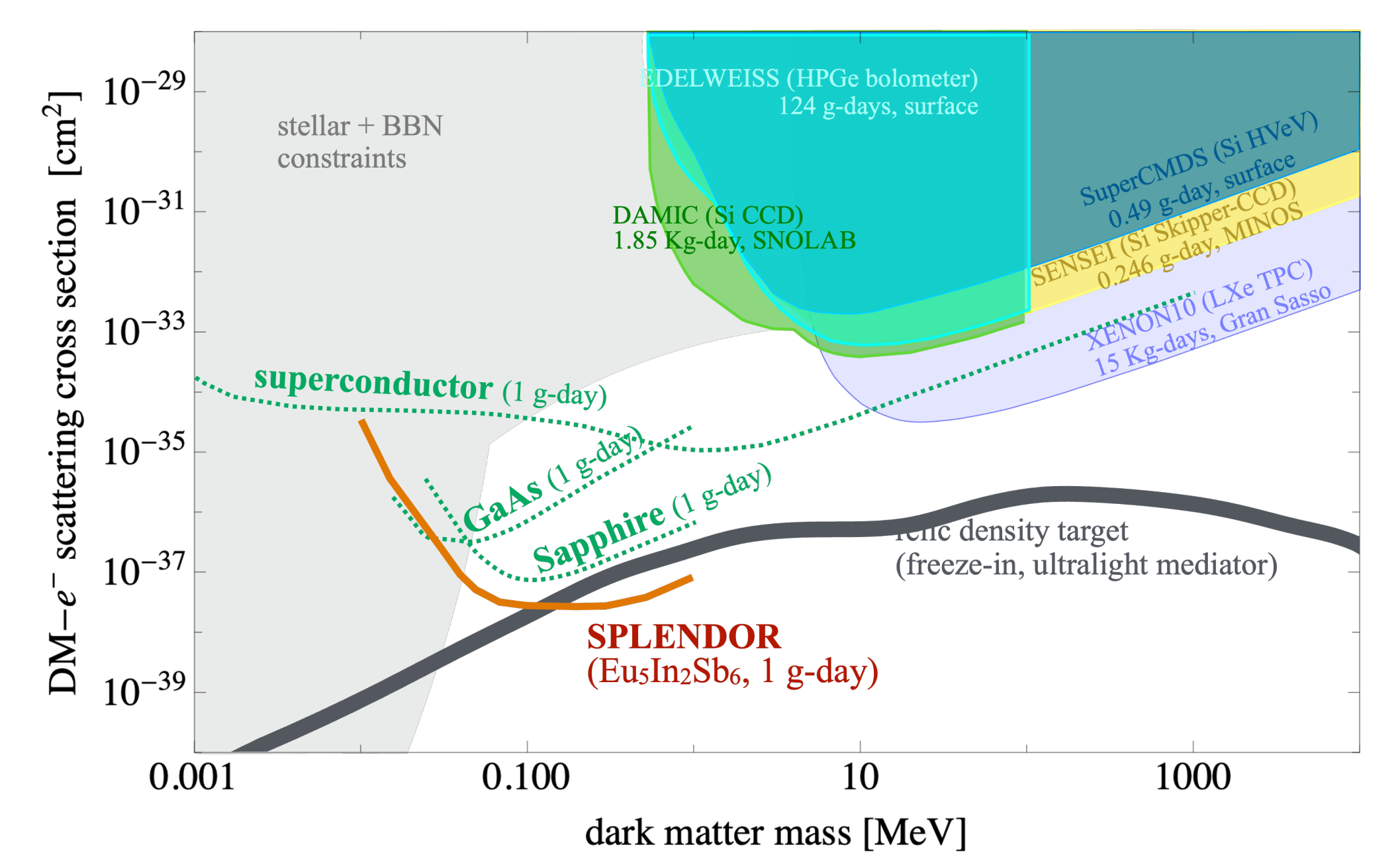
Main Design Challenge: Minimization of parasitic capacitance



Solution: Two-stage HEMT design

Estimated Sensitivity

Assuming a light mediator, with a preliminary dielectric function, SPLENDOR's 90% C.L. sensitivity with no background



THE SPLENDOR TEAM

